



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

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Serial No.: 10/652,796

Filed: August 28, 2003

For: A METHOD FOR MAKING  
A SEMICONDUCTOR  
DEVICE HAVING A HIGH-K  
GATE DIELECTRIC

Art Unit: unknown

Examiner: unknown

Attorney Docket: P17280

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:


This Information Disclosure Statement is being submitted under 37 C.F.R. §1.97(b). Enclosed is a copy of Information Disclosure Citation Form PTO-1449 together with copies of the references cited on that form. It is respectfully requested that the cited references be considered and that the enclosed copy of Information Disclosure Citation Form PTO-1449 be initialed by the Examiner to indicate such consideration and a copy thereof returned to applicant(s).

Pursuant to 37 C.F.R. § 1.97, the submission of this Information Disclosure Statement is not to be construed as a representation that a search has been made

and is not to be construed as an admission that the information cited in this statement constitutes prior art or is otherwise material to patentability.

Respectfully submitted,

Dated: October 30, 2003

  
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(37 C.F.R. § 1.8(a))

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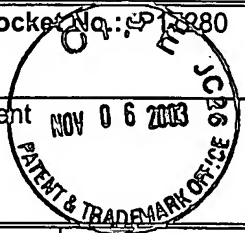
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October 30, 2003

Date

Form PTO-1449 (Modified)		Atty Docket No.: 10/652,796		Serial No.: 10/652,796	
List of Patents and Publications Statement (Use several sheets if necessary)				Applicant: Justin K. Brask et al.	
				Filing Date: August 28, 2003	



REFERENCE DESIGNATION			U.S. PATENT DOCUMENTS			
Examiner Initials		Document No.		Class	Sub-Class	Filing date if appropriate
	AA	6,121,094	Gardner et al.	438	287	
	AB	6,436,777	Ota	438	305	
	AC	6,514,828	Ahn et al.	438	297	
	AD	6,617,209	Chau et al.	438	240	
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	AF	US2002/0197790	Kizilyalli et al.	438	240	
	AG	US2003/0045080	Visokay et al.	438	591	
	AH					
	AI					
	AJ					
	AK					
	AL					
	AM					
	AN					
	AO					
	AP					

FOREIGN PATENT DOCUMENTS							
No.		Document No.	Date	Country	Class	Sub-Class	Translation
	AQ						
	AR						
	AS						
	AT						
	AU						

OTHER ART (Including Author, Title, Date, Pertinent Pages, etc.)		
	AV	Polishchuk et al., "Dual Workfunction CMOS Gate Technology Based on Metal Interdiffusion," <a href="http://www.eesc.berkeley.edu">www.eesc.berkeley.edu</a> , 1 page.
	AW	
	AX	
	AY	
	AZ	

Examiner	Date Considered
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**EXAMINER:** Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.